IN THE CLAIMS:

1. (Original) A display device comprising a transistor and an electrode electrically connected to the transistor,

wherein the electrode comprises a first transparent conductive film comprising indium tin oxide containing one or both of silicon oxide and silicon as the bottom layer, and a second transparent conductive film comprising indium tin oxide as the top layer.

2. (Original) A display device comprising a transistor and an electrode electrically connected to the transistor,

wherein the electrode comprises a first transparent conductive film comprising indium tin oxide containing one or both of silicon oxide and silicon as the bottom layer, and a second transparent conductive film that has a work function of 5.0 eV or more as the top layer.

3 (Original) A display device comprising a transistor and an electrode electrically connected to the transistor,

wherein the electrode comprises a first amorphous transparent conductive film as the bottom layer and a second crystalline transparent conductive film as the top layer.

4. (Original) A display device comprising a transistor and an electrode electrically connected to the transistor,

wherein the electrode comprises a first transparent conductive film comprising amorphous indium tin oxide as the bottom layer and a second transparent conductive film comprising crystalline indium tin oxide as the top layer.

5. (Original) A display device comprising a transistor and an electrode electrically connected to the transistor,

wherein the electrode comprises a first transparent conductive film including oxygen at 61 atomic %, indium at 34 atomic %, tin at 2 atomic %, and silicon at 3 atomic % as the bottom layer, and a second transparent conductive film including oxygen at 62 atomic %, indium at 36 atomic %, and tin at 2 atomic % as the top layer.

6. (Original) The display device according to claim 1, wherein the second transparent conductive film has a film thickness of 30 nm or less.

7. (Original) The display device according to claim 2, wherein the second transparent conductive film has a film thickness of 30 nm or less.

8. (Original) The display device according to claim 3, wherein the second transparent conductive film has a film thickness of 30 nm or less.

9. (Original) The display device according to claim 4, wherein the second transparent conductive film has a film thickness of 30 nm or less.

10. (Original) The display device according to claim 5, wherein the second transparent conductive film has a film thickness of 30 nm or less.

11. (Original) The display device according to claim 1, wherein a terminal portion of a flexible printed circuit has a laminated structure of a conductive film that has a specific resistance of 3μ Ω or less, the first transparent conductive film, and the second transparent conductive film.

12. (Original) The display device according to claim 2, wherein a terminal portion of a flexible printed circuit has a laminated structure of a conductive film that has a specific resistance of 3μ Ω or less, the first transparent conductive film, and the second transparent conductive film.

13. (Original) The display device according to claim 3, wherein a terminal portion of a flexible printed circuit has a laminated structure of a conductive film that has a specific resistance of 3 μ Ω or less, the first transparent conductive film, and the second transparent conductive film.

14. (Original) The display device according to claim 4, wherein a terminal portion of a flexible printed circuit has a laminated structure of a conductive film that has a specific resistance of 3 μ Ω or less, the first transparent conductive film, and the second transparent conductive film.

15. (Original) The display device according to claim 5, wherein a terminal portion of a flexible printed circuit has a laminated structure of a conductive film that has a specific resistance of 3 μ Ω or less, the first transparent conductive film, and the second transparent conductive film.

16. (Original) The display device according to claim 1, wherein a silicon nitride film is provided below the first transparent conductive film.

17. (Original) The display device according to claim 2, wherein a silicon nitride film is provided below the first transparent conductive film.

18. (Original) The display device according to claim 3, wherein a silicon nitride film is provided below the first transparent conductive film.

19. (Original) The display device according to claim 4, wherein a silicon nitride film is provided below the first transparent conductive film.

20. (Original) The display device according to claim 5, wherein a silicon nitride film is provided below the first transparent conductive film.

21.-23. (Cancelled)

24. (Original) The display device according to claim 1, wherein the display device is applied in an electronic device selected from the group consisting of a video camera, a laptop personal computer, a personal digital assistant, a digital camera and a mobile phone.

25. (Original) The display device according to claim 2, wherein the display device is applied in an electronic device selected from the group consisting of a video camera, a laptop personal computer, a personal digital assistant, a digital camera and a mobile phone.

26. (Original) The display device according to claim 3, wherein the display device is applied in an electronic device selected from the group consisting of a video camera, a laptop personal computer, a personal digital assistant, a digital camera and a mobile phone.

27. (Original) The display device according to claim 4, wherein the display device is applied in an electronic device selected from the group consisting of a video camera, a laptop personal computer, a personal digital assistant, a digital camera and a mobile phone.

28. (Original) The display device according to claim 5, wherein the display device is applied in an electronic device selected from the group consisting of a video camera, a laptop personal computer, a personal digital assistant, a digital camera and a mobile phone.

29. (Cancelled)